Nanoscale Hot-Electron Bolometric Detector

\[ \delta E \sim (k_B T^2 C_e)^{1/2} \propto T^{3/2}, V^{1/2} \]

\( \Rightarrow \) Smaller, colder = more sensitive

We have developed a nanoscale superconducting Ti bolometric detector with \( T_c = 0.3 \) K. Nb contacts, with \( T_c = 8 \) K, confine hot electrons in the Ti. Thermal relaxation is set by electron-phonon coupling in the Ti, with a time constant \( \sim \mu s \). [1]

To test a detector with \( \delta E/h \sim \text{THz} \), one needs very precise control of the incident photon flux over a very wide frequency range. For example, a 300 K blackbody presents \( \sim 10^{12} \) photons/sec to a single-mode detector in a 1-2 THz bandwidth.

Experimental Technique: Testing with Fauxtons

A single THz/IR photon is simulated by a fast microwave pulse, where the absorbed energy of the pulse is equal to the photon energy. We call this pulse a faux photon, or fauxton. This technique has several key advantages:
- The device is operated in a cryogenically dark environment with negligible blackbody photons.
- The input coupling efficiency is precisely calibrated in situ using Johnson noise thermometry.
- The fauxton frequency can be tuned simply by adjusting the amplitude of the microwave source.

Readout is achieved by measuring the change in the reflection coefficient with a CW microwave probe. This takes advantage of low-noise amplifiers and isolators available at these frequencies, and is also amenable to frequency-domain multiplexing of a multi-pixel detector array.

Results

Histograms of pulse heights from \( 10^3 \) single-shot measurements for different fauxton energies; the FWHM gives the energy resolution. Also shown is the histogram with the device biased well above \( I_c \), which gives the energy uncertainty due to amplifier noise. We find \( \delta E_{\text{amp}}/h = 43 \pm 1 \) THz and \( \delta E_{\text{amp}}/h = 43 \) THz, and hence \( \delta E_{\text{intrinsic}}/h = 23 \) THz.

The predicted intrinsic energy resolution can be calculated from the NEP: Noise measured at the mixer input, referred to the input of the first stage amplifier. Noise is shown with the device at the optimum bias point for detection and also with the device above \( I_c \), where the dominant noise source is amplifier noise. The measured noise and responsivity correspond to \( \delta E_{\text{amp}}/h = 50 \) THz, consistent with the fauxton measurements.

\[ \delta E_{\text{amp}}/h \sim 1 \] THz is predicted to be achievable by reducing the Ti nanobridge volume and \( T_c \). The fauxton technique avoids several complications of real optical measurements, such as imperfect optical coupling and the loss of energy from the initial photoexcitation before a thermal electron distribution is achieved. Hence, the fauxton technique is not only useful for preliminary device characterization, it can also be used to understand detector nonidealities in real optical experiments.

Outlook

References